

July 2014

FOD8160 High Noise Immunity, 3.3 V / 5 V, 10 Mbit/sec, Logic Gate Optocoupler in Wide-Body SOP 5-Pin

Features

- Optoplanar[®] Packaging Technology Allows More Than 10 mm Creepage and Clearance Distance, and 0.5 mm Insulation Distance to Achieve Reliable and High Voltage Insulation
- High Noise Immunity Characterized by Common Mode Transient Immunity (CMTI)
 20 kV/µs Minimum CMTI
- Specifications Guaranteed Over 3 V to 5.5 V Supply Voltage and -40°C to 100°C Extended Industrial Temperature Range
- High-Speed, 10 Mbit/s Data Rate (NRZ)
- Safety and Regulatory Approvals
 - UL1577, 5,000 VAC_{RMS} for 1 Minute
 - DIN-EN/IEC60747-5-5, 1,414 V Peak Working Insulation Voltage

Applications

- Isolating Intelligent Power Module
- Isolating Industrial Communication Interface

Related Resources

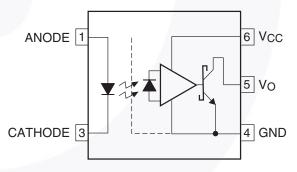
- www.fairchildsemi.com/products/opto/
- www.fairchildsemi.com/pf/FO/FODM8061.html
- www.fairchildsemi.com/pf/FO/FODM611.html

Description

The FOD8160 is a 3.3 V / 5 V high-speed logic gate optocoupler with open-collector output, which supports isolated communications to allow digital signals to communicate between systems without conducting ground loops or hazardous voltages. The device utilizes Fairchild's prioprietary Optoplanar[®] coplanar packaging technology and optimized IC design to achieve high-noise immunity, characterized by high common-mode rejection specifications.

The FOD8160, packaged in a wide-body SOP 5-Pin package, consists of an aluminium gallium arsenide (AlGaAs) LED and an integrated high-speed photodetector. The output of the detector IC is an open collector Schottky-clamped transistor. The electrical and switching characteristics are guaranteed over the extended industrial temperature range of -40°C to 100°C and a V_{CC} range of 3 V to 5.5 V.

Functional Schematic



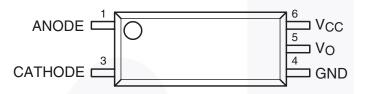


©2012 Fairchild Semiconductor Corporation FOD8160 Rev. 1.0.2

Truth Table

| LED | Output |
|-----|--------|
| Off | HIGH |
| On | LOW |

Pin Configuration



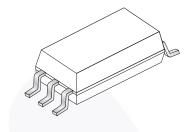


Figure 2. Pin Configuration

Pin Definitions

| Pin # | Name | Description |
|-------|-----------------|-----------------------|
| 1 | Anode | Anode |
| 3 | Cathode | Cathode |
| 4 | GND | Output Ground |
| 5 | Vo | Output Voltage |
| 6 | V _{CC} | Output Supply Voltage |

Safety and Insulation Ratings

As per DIN EN/IEC60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data below. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Symbol | Parameter | Min. | Тур. | Max. | Unit |
|-----------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|-----------|------|-------------------|
| | Installation Classifications per DIN VDE 0110/1.89 Table 1 | | | | |
| | For Rated Mains Voltage < 150 V _{RMS} | | I–IV | | |
| | For Rated Mains Voltage < 300 V _{RMS} | | I–IV | | 1 |
| | For Rated Mains Voltage < 450 V _{RMS} | | I–IV | | |
| | For Rated Mains Voltage < 600 V _{RMS} | | I–IV | | |
| | Climatic Classification | | 40/100/21 | | |
| | Pollution Degree (DIN VDE 0110/1.89) | | 2 | | |
| CTI | Comparative Tracking Index | 175 | | | |
| V _{PR} | Input to Output Test Voltage, Method b, $V_{IORM} \times 1.875 = V_{PR}$, 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC | 2651 | | | V _{peak} |
| | Input to Output Test Voltage, Method a, $V_{IORM} \times 1.6 = V_{PR}$, Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC | 2262 | | | V _{peak} |
| VIORM | Maximum Working Insulation Voltage | 1414 | | | V _{peak} |
| V _{IOTM} | Highest Allowable Over Voltage | 8000 | | | V _{peak} |
| | External Creepage | 10.0 | | | mm |
| | External Clearance | 10.0 | | | mm |
| | Insulation Thickness | 0.5 | | | mm |
| | Safety Limit Values – Maximum Values Allowed in the Event of a Failure | | | | |
| Τ _S | Case Temperature | 150 | | | °C |
| I _{S,INPUT} | Input Current | 200 | | | mA |
| P _{S,OUTPUT} | Output Power | 600 | | | mW |
| R _{IO} | Insulation Resistance at T _S , V _{IO} = 500 V | 10 ⁹ | | | Ω |

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^{\circ}C$ unless otherwise specified.

| Symbol | Parameter | Value | Units |
|------------------|-----------------------------------------------------------------------------|-------------------------------|-------|
| T _{STG} | Storage Temperature | -40 to +125 | °C |
| T _{OPR} | Operating Temperature | -40 to +100 | °C |
| TJ | Junction Temperature | -40 to +125 | °C |
| T _{SOL} | Lead Solder Temperature (Refer to Reflow Temperature Profile on page 12) | 260 for 10 seconds | °C |
| Input Characteri | istics | | |
| ١ _F | Average Forward Input Current | 25 | mA |
| V _R | Reverse Input Voltage | 5.0 | V |
| PDI | Input Power Dissipation ⁽¹⁾ | 45 | mW |
| Output Characte | eristics | | |
| V _{CC} | Supply Voltage | 0 to 7.0 | V |
| V _O | Output Voltage | -0.5 to V _{CC} + 0.5 | V |
| Ι _Ο | Average Output Current | 50 | mA |
| PD _O | Output Power Dissipation ⁽¹⁾ | 85 | mW |

Note:

1. No derating required up to 100°C.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter | Min. | Max. | Unit |
|-----------------|---------------------------------|------|------|-----------|
| T _A | Ambient Operating Temperature | -40 | +100 | °C |
| V _{CC} | Supply Voltages ⁽²⁾ | 3.0 | 5.5 | V |
| V _{FL} | Logic Low Input Voltage | 0 | 0.8 | V |
| I _{FL} | Logic Low Input Current | | 250 | μA |
| I _{FH} | Logic High Input Current | 6.0 | 15 | mA |
| N | Fan Out (at $R_L = 1 k\Omega$) | | 5 | TTL loads |
| RL | Output Pull-up Resistor | 330 | 4000 | Ω |

Note:

2. 0.1 μF bypass capacitor must be connected between pins 4 and 6.

Isolation Characteristics

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units |
|------------------|-----------------------------------|-------------------------------------------------------------------------------------------------------------------------|-------|------------------|------|--------------------|
| V _{ISO} | Input-Output Isolation Voltage | $\begin{array}{l} T_{A} = 25^{\circ}C, \ R.H. < 50\%, \ t = 1.0 \ min, \\ I_{I-O} \leq 20 \ \mu A^{(3)(4)} \end{array}$ | 5,000 | | | VAC _{RMS} |
| R _{ISO} | Isolation Resistance | $V_{I-O} = 500 V^{(3)}$ | | 10 ¹¹ | | Ω |
| C _{ISO} | Isolation Capacitance | V_{I-O} = 0 V, frequency = 1.0 MHz ⁽³⁾ | | 1.0 | | pF |

Apply over all recommended conditions, typical value is measured at $T_A = 25^{\circ}C$.

Notes:

3. Device is considered a two-terminal device: pins 1 and 3 are shorted together and pins 4, 5, and 6 are shorted together.

4. 5,000 VAC_{RMS} for 1-minute duration is equivalent to 6,000 VAC_{RMS} for 1-second duration.

Electrical Characteristics

Apply over all recommended conditions; $T_A = -40^{\circ}C$ to $+100^{\circ}C$, $3.0 \text{ V} \le V_{CC} \le 5.5 \text{ V}$; unless otherwise specified. Typical value is measured at $T_A = 25^{\circ}C$ and $V_{CC} = 3.3 \text{ V}$ or $V_{CC} = 5 \text{ V}$.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units | Figure |
|---------------------------------------------|--------------------------------------------|-----------------------------------------------------------------------------|------|------|------|-------|--------|
| Input Chara | cteristics | | | | | | |
| V _F | Forward Voltage | I _F = 10 mA | 1.05 | 1.45 | 1.80 | V | 3 |
| Δ (V _F / T _A) | Temperature Coefficient of Forward Voltage | | | -1.8 | | mV/°C | |
| BV _R | Input Reverse Breakdown Voltage | I _R = 10 μA | 5.0 | | | V | |
| I _{FHL} | Threshold Input Current | V _O = 0.6 V, I _{OL} (sink) = 13 mA | | 2.5 | 6.0 | mA | 4 |
| Output Chai | racteristics | | | | | | |
| V _{OL} | Logic Low Output Voltage | I _F = rated I _{FHL} , I _{OL} (sink) = 13 mA | | 0.4 | 0.6 | V | 5 |
| I _{OH} | Logic High Output | I _F = 250 μA, V _O = 3.3 V | | 8.0 | 50.0 | μA | 6 |
| | Current | I _F = 250 μA, V _O = 5.0 V | | 3.0 | 40.0 | μA | 6 |
| I _{CCL} | Logic Low Output | I _F = 10 mA, V _{CC} = 3.3 V | | 5.3 | 8.5 | mA | 7, 9 |
| | Supply Current | I _F = 10 mA, V _{CC} = 5.0 V | | 7.1 | 10.0 | mA | 7, 9 |
| I _{CCH} | Logic High Output | I _F = 0 mA, V _{CC} = 3.3 V | | 3.5 | 7.0 | mA | 8, 9 |
| | Supply Current | I _F = 0 mA, V _{CC} = 5.0 V | | 5.3 | 9.0 | mA | 8, 9 |

Switching Characteristics

Apply over all recommended conditions; $T_A = -40^{\circ}$ C to +100°C, $V_{CC} = 3.3$ V, $I_F = 6.0$ mA; unless otherwise specified. Typical value is measured at $T_A = 25^{\circ}$ C and $V_{CC} = 3.3$ V.

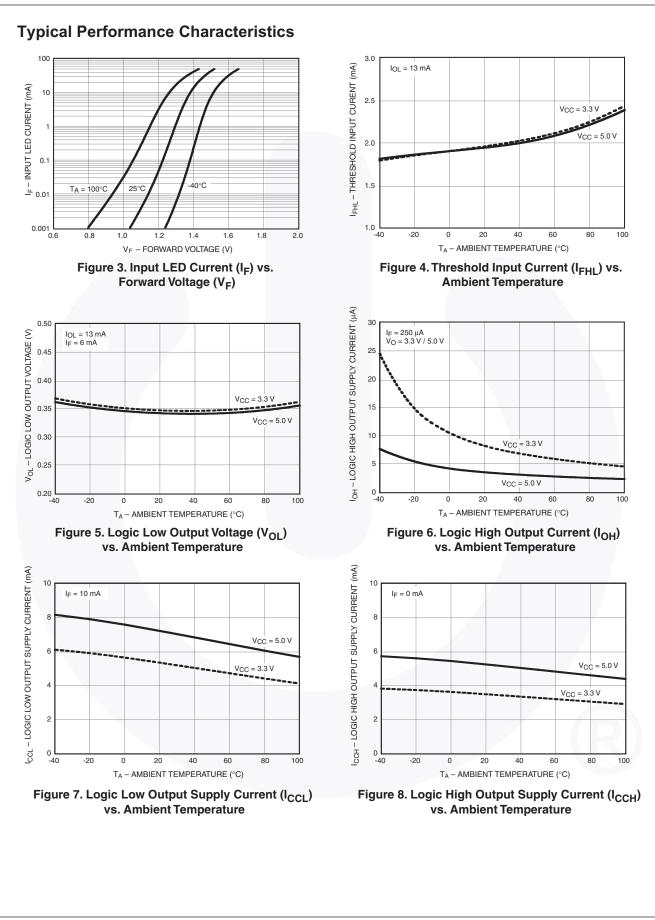
| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units | Figure |
|------------------|------------------------------------------------------------------|----------------------------------------------------------------------------------------------|------|------|------|----------|---------------|
| Data Rate | | R _L = 350 Ω | | | 10 | Mbit/sec | |
| t _{PHL} | Propagation Delay to Logic Low Output | R _L = 350 Ω, C _L = 15 pF | | 40 | 80 | ns | 10, 11, 15 |
| t _{PLH} | Propagation Delay to Logic High Output | R _L = 350 Ω, C _L = 15 pF | | 50 | 90 | ns | 10, 11, 15 |
| PWD | Pulse Width Distortion, t _{PHL} – t _{PLH} | R _L = 350 Ω, C _L = 15 pF | | 10 | 35 | ns | 12, 13, 15 |
| t _{PSK} | Propagation Delay Skew | $R_{L} = 350 \ \Omega, C_{L} = 15 \ pF$ | | | 40 | ns | |
| t _R | Output Rise Time (10% to 90%) | R _L = 350 Ω, C _L = 15 pF | | 20 | | ns | 14, 15 |
| t _F | Output Fall Time (90% to 10%) | R _L = 350 Ω, C _L = 15 pF | | 10 | | ns | 14, 15 |
| CM _H | Common-Mode Transient Immunity at Output High | $I_{\rm F} = 0 \text{ mA, } V_{\rm O} > 2 \text{ V,} \\ V_{\rm CM} = 1,000 \text{ V}^{(6)}$ | 20 | 40 | | kV/µs | 16 |
| CM _L | Common-Mode Transient Immunity at Output Low | I _F = 6.0 mA, V _O < 0.8 V, V _{CM} = 1,000 V ⁽⁶⁾ | 20 | 40 | | kV/µs | 16 |

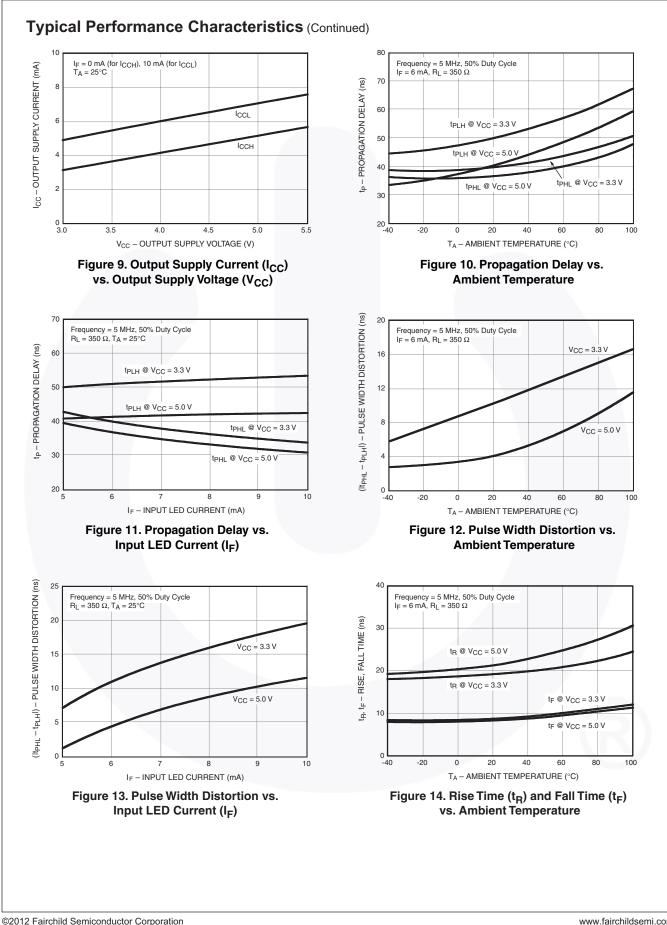
Apply over all recommended conditions; $T_A = -40^{\circ}$ C to $+100^{\circ}$ C, $V_{CC} = 5$ V, $I_F = 6.0$ mA; unless otherwise specified. Typical value is measured at $T_A = 25^{\circ}$ C and $V_{CC} = 5$ V.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Units | Figure |
|------------------|-----------------------------------------------------|------------------------------------------------------------------------------------------------|------|------|------|----------|---------------|
| Data Rate | | R _L = 350 Ω | | | 10 | Mbit/sec | |
| t _{PHL} | Propagation Delay to Logic Low Output | R _L = 350 Ω, C _L = 15 pF | | 37 | 80 | ns | 10, 11, 15 |
| t _{PLH} | Propagation Delay to Logic High Output | R _L = 350 Ω, C _L = 15 pF | | 41 | 90 | ns | 10, 11, 15 |
| PWD | Pulse Width Distortion, $ t_{PHL} - t_{PLH} $ | R _L = 350 Ω, C _L = 15 pF | | 4 | 25 | ns | 12, 13, 15 |
| t _{PSK} | Propagation Delay Skew | R_L = 350 Ω, C_L = 15 pF ⁽⁵⁾ | | | 40 | ns | |
| t _R | Output Rise Time (10% to 90%) | R _L = 350 Ω, C _L = 15 pF | | 22 | | ns | 14, 15 |
| t _F | Output Fall Time (90% to 10%) | R _L = 350 Ω, C _L = 15 pF | | 9 | | ns | 14, 15 |
| CM _H | Common-Mode Transient Immunity at Output High | $I_{\rm F} = 0 \text{ mA, } V_{\rm O} > 2 \text{ V,} \\ V_{\rm CM} = 1,000 \text{ V}^{(6)}$ | 20 | 40 | | kV/µs | 16 |
| CM _L | Common-Mode Transient Immunity at Output Low | $I_{\rm F} = 6.0 \text{ mA}, V_{\rm O} < 0.8 \text{ V}, \\ V_{\rm CM} = 1,000 \text{ V}^{(6)}$ | 20 | 40 | | kV/µs | 16 |

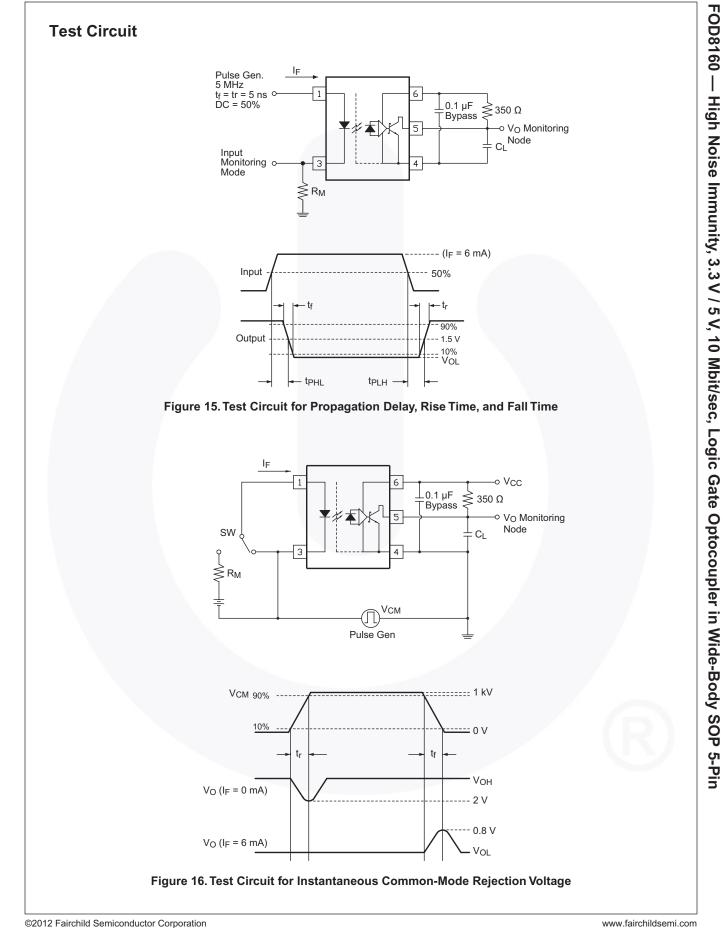
Notes:

- 5. t_{PSK} is equal to the magnitude of the worst-case difference in t_{PHL} and/or t_{PLH} between any two units from the same manufacturing date code that are operated at same case temperature (±5°C), at same operating conditions, with equal loads (R_L = 350 Ω , C_L = 15 pF), and with an input rise time less than 5 ns.
- Common-mode transient immunity at output HIGH is the maximum tolerable positive dVcm/dt on the leading edge of the common-mode impulse signal, V_{CM}, to assure that the output remains HIGH. Common-mode transient immunity at output LOW is the maximum tolerable negative dVcm/dt on the trailing edge of the common pulse signal, V_{CM}, to assure that the output remains LOW.





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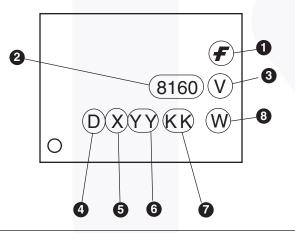
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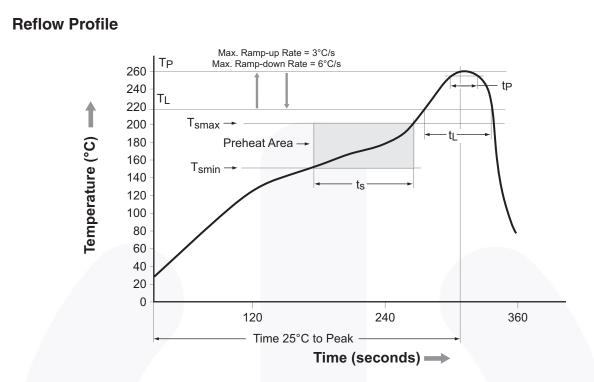
| Part Number | Package | Packing Method |
|-------------|--------------------------------------------------|--------------------------------------|
| FOD8160 | Wide Body SOP 5-Pin | Tube (100 units per tube) |
| FOD8160R2 | Wide Body SOP 5-Pin | Tape and Reel (1,000 units per reel) |
| FOD8160V | Wide Body SOP 5-Pin, DIN EN/IEC60747-5-5 Option | Tube (100 units per tube) |
| FOD8160R2V | Wide Body SOP 5-Pin, DIN EN/ IEC60747-5-5 Option | Tape and Reel (1,000 units per reel) |

All packages are lead free per JEDEC: J-STD-020B standard.

Marking Information

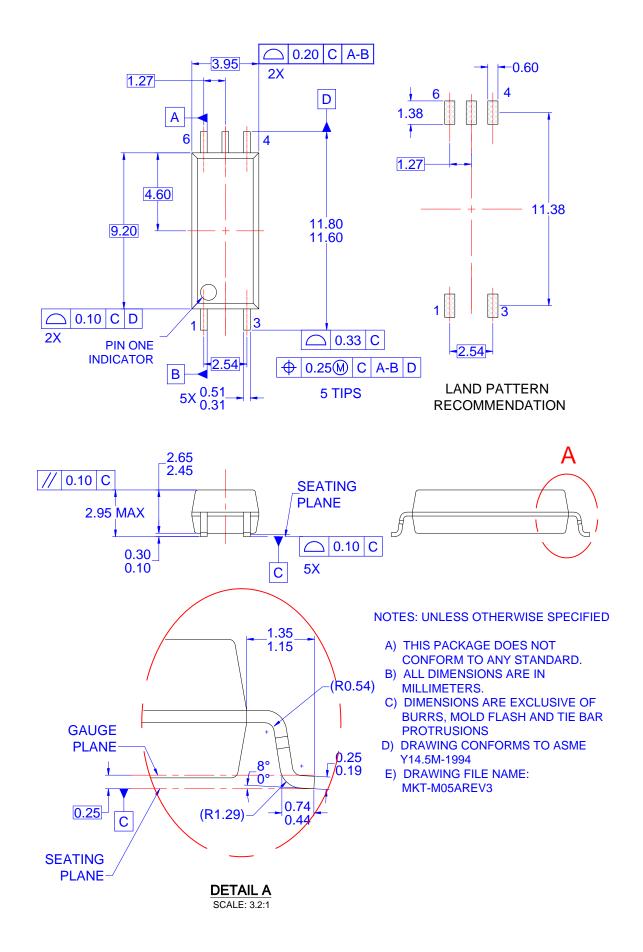


| Defini | Definitions | | | | |
|--------|---------------------------------------------------------------------------------|--|--|--|--|
| 1 | Fairchild logo | | | | |
| 2 | Device number, e.g., '8160' for FOD8160 | | | | |
| 3 | DIN EN/IEC60747-5-5 option (only appears on component ordered with this option) | | | | |
| 4 | Plant code, e.g., 'D' | | | | |
| 5 | Last-digit year code, e.g., 'E' for 2014 | | | | |
| 6 | Two-digit work week ranging from '01' to '53' | | | | |
| 7 | Lot-traceability code | | | | |
| 8 | Package assembly code, W | | | | |



| Figure | 17. | Reflow | Profile |
|--------|-----|--------|---------|
|--------|-----|--------|---------|

| Profile Freature | Pb-Free Assembly Profile |
|-----------------------------------------------------|--------------------------|
| Temperature Minimum (T _{smin}) | 150°C |
| Temperature Maximum (T _{smax}) | 200°C |
| Time (t_S) from $(T_{smin} \text{ to } T_{smax})$ | 60 to 120 seconds |
| Ramp-Up Rate (t _L to t _P) | 3°C/second maximum |
| Liquidous Temperature (T _L) | 217°C |
| Time (t_L) Maintained Above (T_L) | 60 to 150 seconds |
| Peak Body Package Temperature | 260°C +0°C / –5°C |
| Time (t _P) within 5°C of 260°C | 30 seconds |
| Ramp-Down Rate (T _P to T _L) | 6°C/second maximum |
| Time 25°C to Peak Temperature | 8 minutes maximum |



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